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April 1<sup>st</sup>, 2010 Renesas Electronics Corporation

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# MOS FIELD EFFECT TRANSISTOR $\mu$ PA2721AGR

# SWITCHING N-CHANNEL POWER MOS FET

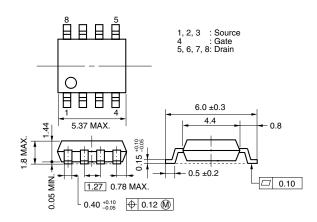
#### **DESCRIPTION**

The  $\mu$ PA2721AGR is N-channel MOS Field Effect Transistor designed for power management applications of a notebook computer.

#### **FEATURES**

- Low on-state resistance
  - $R_{DS(on)1}$  = 4.3 m $\Omega$  MAX. (Vgs = 10 V, Ip = 10 A)
- $R_{DS(on)2} = 10 \text{ m}\Omega \text{ MAX.} \text{ (V}_{GS} = 5.0 \text{ V}, I_{D} = 10 \text{ A)}$
- Low input capacitance
  - $C_{iss} = 7100 \text{ pF TYP.} (V_{DS} = 10 \text{ V}, V_{GS} = 0 \text{ V})$
- Built-in gate protection diode
- Small and surface mount package (Power SOP8)
- RoHS Compliant

#### PACKAGE DRAWING (Unit: mm)



#### **ORDERING INFORMATION**

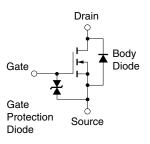
PART NUMBER	LEAD PLATING	PACKING	PACKAGE		
μPA2721AGR-E1-AT Note	Duna Ca	T 0500 -/	Power SOP8		
μPA2721AGR-E2-AT Note	Pure Sn	Tape 2500 p/reel	0.08 g TYP.		

Note Pb-free (This product does not contain Pb in external electrode and other parts.)

#### ABSOLUTE MAXIMUM RATINGS (TA = 25°C, All terminals are connected.)

Drain to Source Voltage (Vgs = 0 V)	VDSS	30	V
Gate to Source Voltage (VDS = 0 V)	Vgss	±20	V
Drain Current (DC)	$I_{D(DC)}$	±19	Α
Drain Current (pulse) Note1	ID(pulse)	±200	Α
Total Power Dissipation Note2	P <sub>T1</sub>	1.1	W
Total Power Dissipation (PW = 10 sec) Note2	P <sub>T2</sub>	2.5	W
Channel Temperature	Tch	150	°C
Storage Temperature	Tstg	-55 to +150	°C
Single Avalanche Current Note3	las	19	Α
Single Avalanche Energy Note3	Eas	36	mJ

#### **EQUIVALENT CIRCUIT**



- **Notes 1.** PW  $\leq$  10  $\mu$ s, Duty Cycle  $\leq$  1%
  - 2. Mounted on glass epoxy board of 25.4 mm x 25.4 mm x 0.8 mmt
  - 3. Starting T<sub>ch</sub> = 25°C, V<sub>DD</sub> = 15 V, R<sub>G</sub> = 25  $\Omega$ , V<sub>GS</sub> = 20  $\rightarrow$  0 V, L = 100  $\mu$ H

**Remark** The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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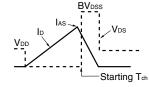
#### ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C, All terminals are connected.)

CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	IDSS	V <sub>DS</sub> = 30 V, V <sub>GS</sub> = 0 V			1	μA
Gate Leakage Current	Igss	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$			±10	μΑ
Gate to Source Cut-off Voltage	V <sub>GS(off)</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 1 mA	1.5		3.0	V
Forward Transfer Admittance Note	yfs	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 10 A	11			S
Drain to Source On-state Resistance Note	R <sub>DS(on)1</sub>	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 10 A		3.6	4.3	mΩ
	R <sub>DS(on)2</sub>	V <sub>GS</sub> = 5.0 V, I <sub>D</sub> = 10 A		4.7	10	mΩ
Input Capacitance	Ciss	V <sub>DS</sub> = 10 V,		7100		pF
Output Capacitance	Coss	V <sub>GS</sub> = 0 V,		930		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		490		pF
Turn-on Delay Time	t <sub>d(on)</sub>	V <sub>DD</sub> = 15 V, I <sub>D</sub> = 10 A,		33		ns
Rise Time	tr	V <sub>GS</sub> = 10 V,		31		ns
Turn-off Delay Time	t <sub>d(off)</sub>	R <sub>G</sub> = 10 Ω		112		ns
Fall Time	tf			32		ns
Total Gate Charge	Q <sub>G</sub>	V <sub>DD</sub> = 15 V,		52		nC
Gate to Source Charge	Qgs	V <sub>GS</sub> = 5 V,		20		nC
Gate to Drain Charge	Q <sub>GD</sub>	I <sub>D</sub> = 19 A		20		nC
Body Diode Forward Voltage Note	V <sub>F(S-D)</sub>	I <sub>F</sub> = 19 A, V <sub>GS</sub> = 0 V		0.8		٧
Reverse Recovery Time	trr	I <sub>F</sub> = 19 A, V <sub>GS</sub> = 0 V,		41		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A/μs		44		nC

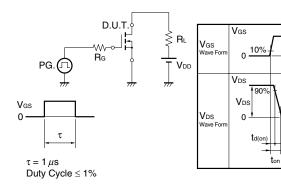
Note Pulsed

#### **TEST CIRCUIT 1 AVALANCHE CAPABILITY**

# $V_{GS} = 20 \rightarrow 0 \text{ V}$ $PG. \bigcirc S = 20 \rightarrow 0 \text{ V}$ $PG. \bigcirc S = 20 \rightarrow 0 \text{ V}$ $PG. \bigcirc S = 20 \rightarrow 0 \text{ V}$ $PG. \bigcirc S = 20 \rightarrow 0 \text{ V}$ $PG. \bigcirc S = 20 \rightarrow 0 \text{ V}$ $PG. \bigcirc S = 20 \rightarrow 0 \text{ V}$ $PG. \bigcirc S = 20 \rightarrow 0 \text{ V}$ $PG. \bigcirc S = 20 \rightarrow 0 \text{ V}$ $PG. \bigcirc S = 20 \rightarrow 0 \text{ V}$ $PG. \bigcirc S = 20 \rightarrow 0 \text{ V}$ $PG. \bigcirc S = 20 \rightarrow 0 \text{ V}$ $PG. \bigcirc S = 20 \rightarrow 0 \text{ V}$



#### **TEST CIRCUIT 2 SWITCHING TIME**



#### **TEST CIRCUIT 3 GATE CHARGE**

$$\begin{array}{c|c} D.U.T. \\ \hline I_G = 2 \text{ mA} \\ \hline \hline W. \\ \hline \end{array}$$

$$\begin{array}{c|c} PG. \\ \hline \end{array}$$

$$\begin{array}{c|c} PG. \\ \hline \end{array}$$

$$\begin{array}{c|c} O.U.T. \\ \hline \end{array}$$

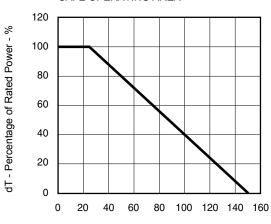
$$\begin{array}{c|c} \hline \\ \hline \\ \hline \end{array}$$

$$\begin{array}{c|c} V_{DD} \\ \hline \end{array}$$

 $\mu$ PA2721AGR

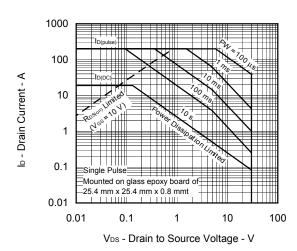
#### TYPICAL CHARACTERISTICS (T<sub>A</sub> = 25°C)

## DERATING FACTOR OF FORWARD BIAS SAFE OPERATING AREA

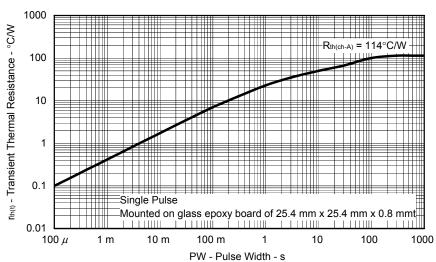


T<sub>A</sub> - Ambient Temperature - °C

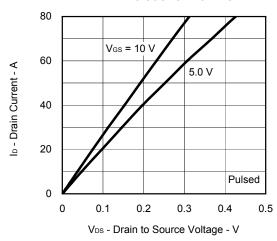
#### FORWARD BIAS SAFE OPERATING AREA



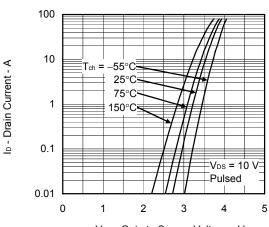
#### TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH



#### DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE



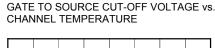
#### FORWARD TRANSFER CHARACTERISTICS

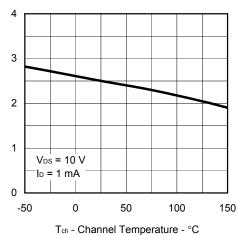


 $\ensuremath{\mathsf{V}}_\text{GS}$  - Gate to Source Voltage -  $\ensuremath{\mathsf{V}}$ 

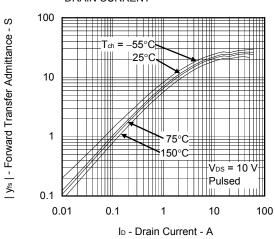
Ves(off) - Gate to Source Cut-off Voltage - V

R<sub>DS(on)</sub> - Drain to Source On-state Resistance - mΩ

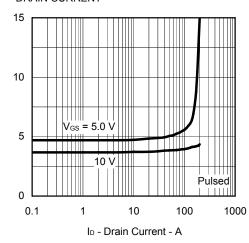




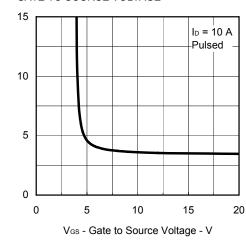
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



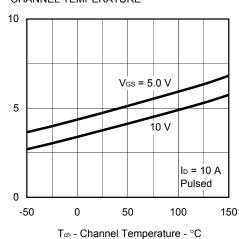
DRAIN TO SOURCE ON-STATE RESISTANCE vs. **DRAIN CURRENT** 



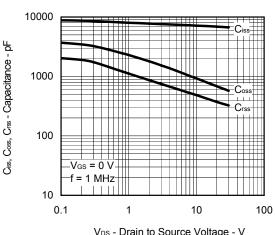
DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE



CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



VDS - Drain to Source Voltage - V

 $\mathsf{R}_{\mathsf{DS}(\mathsf{on})}$  - Drain to Source On-state Resistance -  $m\Omega$ 

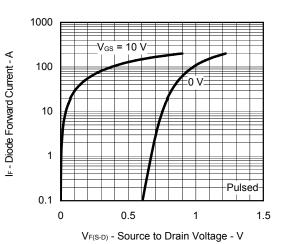
R<sub>DS(m)</sub> - Drain to Source On-state Resistance - mΩ

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#### DYNAMIC INPUT/OUTPUT CHARACTERISTICS

#### 30 6 V<sub>DS</sub> - Drain to Source Voltage - V V<sub>GS</sub> - Gate to Source Voltage - V V<sub>DD</sub> = 24 V 5 20 10 ID = 19 A 0 0 0 60 20 40 Q<sub>G</sub> - Gate Charge - nC

#### SOURCE TO DRAIN DIODE FORWARD VOLTAGE



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